



MDWC12D025ERH

Common-Drain Dual N-Channel Trench MOSFET 12V, 2.55 mΩ

General Description

The MDWC12D025ERH uses advanced Magnachip's MOSFET Technology, which provides high performance in on-state resistance and excellent reliability. Excellent low $R_{\text{SS(ON)}}$, low gate charge operation and operation for Battery Application.

Features

- Vss = 12V
- Source-Source ON Resistance;

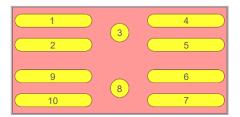
 $\begin{array}{ll} R_{SS(ON)}\,<\,2.30 m\Omega & \textcircled{Q}\,\,V_{GS}=4.5V \\ R_{SS(ON)}\,<\,2.55 m\Omega & \textcircled{Q}\,\,V_{GS}=3.8V \\ R_{SS(ON)}\,<\,3.75 m\Omega & \textcircled{Q}\,\,V_{GS}=3.1V \end{array}$

 $Rss(ON) < 5.80m\Omega$ @ Vgs = 2.5V

Applications

- Portable Battery Protection

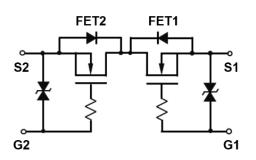
Bottom View



2.98mm x 1.49mm WLCSP

1, 2, 4, 5 : Source1(FET1) 3 : Gate1(FET1) 6, 7, 9, 10 : Source2(FET2) 8 : Gate2(FET2)

Equivalent circuit



Absolute Maximum Ratings

Characteristics		Symbol	Rating	Units
Source-Source Voltage		V _{SSS}	12	V
Gate-Source Voltage		V _{GSS}	±8	V
Source Current	DC*1	Is	23.2	Α
	Pulse	I _{SP}	92.8	Α
Total Power Dissipation	Total Power Dissipation DC*1		2.2	W
Channel Temperature		T _{ch}	-55~150	°C
Junction and Storage Temperature Range		T_J,T_stg	-55~150	°C

Thermal Characteristics

Characteristics	Symbol	Rating	Unit
Thermal Resistance ^{*1}	$R_{\theta JA}$	65	°C/W

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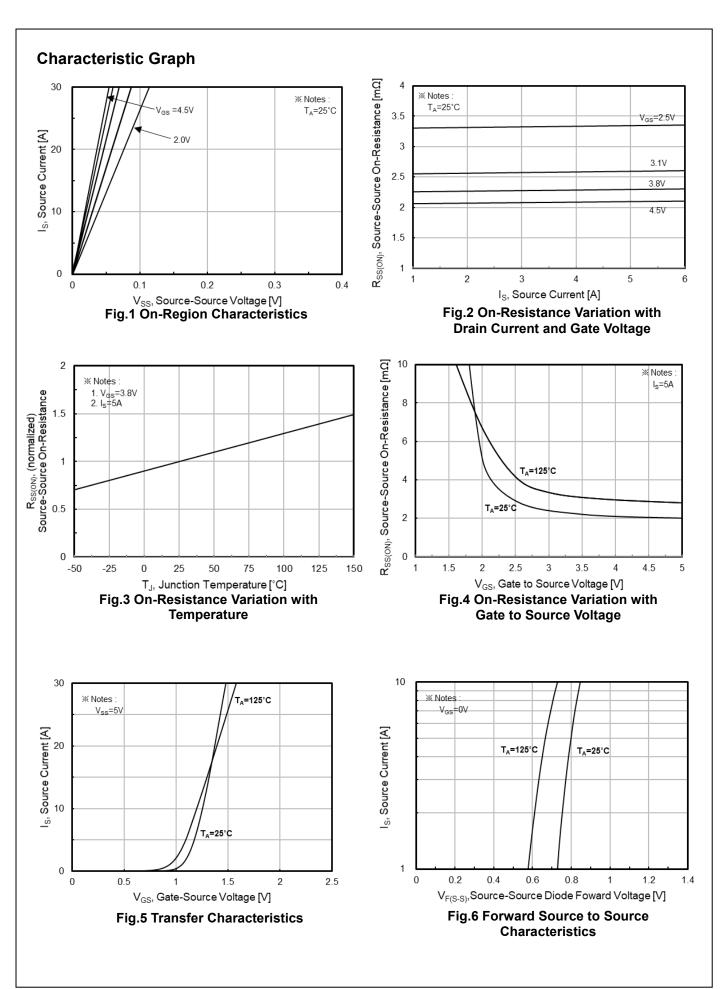
Ordering Information

Part Number	Temp. Range	Package	Packing	RoHS Status
MDWC12D025ERH	-55~150 °C	WLCSP	Tape and Reel	Halogen Free

Electrical Characteristics (T_A =25°C unless otherwise noted)

Characteristics	Symbol	Test Condition	Min	Тур	Max	Units
Static Characteristics						
Source-Source Breakdown Voltage	BV _{SSS}	I _S = 250uA, V _{GS} = 0V	12	-	-	- V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{SS} = V_{GS}$, $I_S = 250uA$	0.4	0.85	1.3	
Cut-Off Current	I _{SSS}	V _{SS} = 12V, V _{GS} = 0V	-	-	1	μΑ
Gate Leakage Current	I _{GSS} 1	$V_{GS} = \pm 8V$, $V_{SS} = 0V$	-	-	10	μА
	I _{GSS} 2	$V_{GS} = \pm 5V$, $V_{SS} = 0V$	-	-	1	
		V _{GS} = 4.5V, I _S = 5.0A	-	1.75	2.30	mΩ
	_	V _{GS} = 3.8V, I _S = 5.0A	-	1.95	2.55	
Source-Source Resistance	$R_{SS(ON)}$	$V_{GS} = 3.1V, I_{S} = 5.0A$	-	2.25	3.75	
		V _{GS} = 2.5V, I _S = 5.0A	-	2.90	5.80	
Dynamic Characteristics			•	•		•
Total Gate Charge	Q_g	V _{DD} = 6V, I _S = 5.0A, V _{GS} = 3.8V	-	25.1	-	nC
Gate-Source Charge	Q_{gs}		-	4.3	-	
Gate-Drain Charge	Q_{gd}		-	10.4	-	
Input Capacitance	C _{iss}		-	3,496	-	pF
Reverse Transfer Capacitance	C _{rss}	$V_{SS} = 6V, V_{GS} = 0V, f = 50kHz$	-	872	-	
Output Capacitance	Coss		-	1,080	-	
Turn-On Delay Time	$t_{d(on)}$		-	0.02	-	
Rise Time	t _r	$V_{GS} = 3.8V, V_{DD} = 6V,$ $I_{S} = 5.0A, R_{GEN} = 3\Omega$	-	0.25	-	μS
Turn-Off Delay Time	$t_{d(off)}$		-	5.54	-	
Fall Time	t _f	1	-	14.64	-	
Drain-Source Body Diode Characteristic	s					•
Source-Source Diode Forward Voltage	VF _(S-S)	I _F = 5A, V _{GS} = 0V	-	0.75	1.2	V

Note *1. Test on PCB board (60.0mm x 24.0mm x 1.0t)



Characteristic Graph

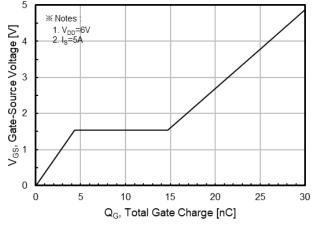


Fig.7 Gate Charge Characteristics

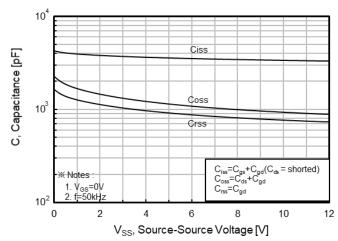


Fig.8 Capacitance Characteristics

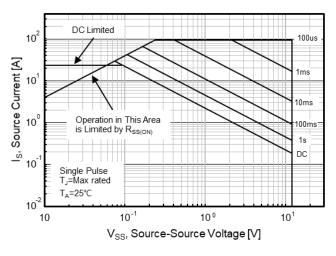


Fig.9 Maximum Safe Operating Area

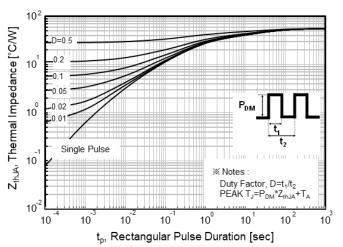
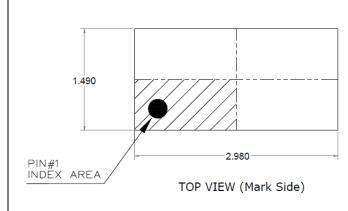
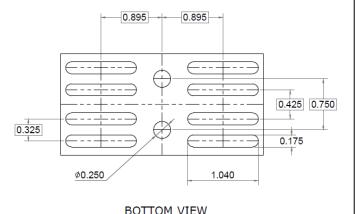
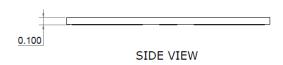


Fig.10 Transient Thermal Response Curve

PACKAGE OUTLINE







NOTES:

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. GENERAL TOLERANCE: ±0.03mm
- 3. PACKAGE BODY SIZES EXCLUDE FLASH & BURRS

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The Products are not designed for use in hostile environments, including, without limitation, aircraft, nuclear power generation, medical appliances, and devices or systems in which malfunction of any Product can reasonably be expected to result in a personal injury. Seller's customers using or selling Seller's products for use in such applications do so at their own risk and agree to fully defend and indemnify Seller.

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